Diode Semiconductor Device - Page 1 of 1



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# Inclosure Material:

Glass

## Overall Length:

Between 0.140 inches and 0.195 inches

## Terminal Length:

Between 0.900 inches and 1.300 inches

## **Overall Diameter:**

Between 0.135 inches and 0.185 inches

## **Function For Which Designed:**

Transient suppressor

#### **End Application:**

Data multiplex system an/usq-82c

## **Mounting Method:**

Terminal

**Features Provided:** 

## Quality assurance level tx and hermetically sealed case

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

13.0 breakdown voltage, dc and 9.9 working peak reverse voltage

## Voltage Tolerance In Percent:

-5.0/+5.0

## Current Rating Per Characteristic:

100.00 milliamperes collector current, dc horsepower metric and 20.00 microamperes forward current, average peak

## **Power Rating Per Characteristic:**

3.0 watts small-signal input power, common-collector major

## Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

## **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## Terminal Type And Quantity:

2 uninsulated wire lead

## **Specification Data:**

81349-mil-s-19500/516 government specification

## Shelf Life:

N/a

Unit Of Measure:

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# Demilitarization:

No

Fiig:

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